

SN74LVC125A-Q1 車載用クワッド バス バッファ ゲート、 3 ステート出力

1 特長

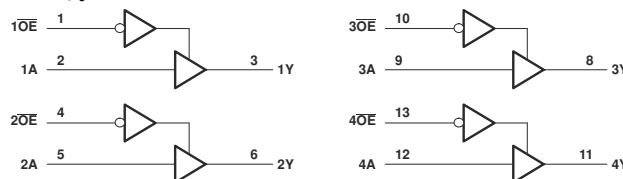
- 車載アプリケーション認定済み
- 1.65V ~ 3.6V で動作
- -40°C ~ 125°C で動作が規定
- 5.5V までの入力電圧に対応
- 最大 t_{pd} : 4.8ns (3.3V 時)
- 標準 V_{OLP} (出力グランド バウンス) < 0.8V (V_{CC} = 3.3V、 T_A = 25°C)
- 標準 V_{OHV} (出力 V_{OH} アンダーシュート) > 2V (V_{CC} = 3.3V、 T_A = 25°C)
- JESD 17 準拠で 250mA 超のラッチアップ性能

2 概要

このクワッド バス バッファ ゲートは、1.65V ~ 3.6V の V_{CC} で動作するように設計されています。

部品番号	パッケージ ⁽¹⁾	パッケージ サイズ ⁽²⁾	本体サイズ ⁽³⁾
SN74LVC125A-Q1	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm
	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.91mm
	PW (TSSOP, 14)	5.00mm × 6.4mm	5.00mm × 4.40mm

- (1) 詳細については、[セクション 10](#) を参照してください。
- (2) パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。
- (3) 本体サイズ (長さ × 幅) は公称値であり、ピンは含まれません。



論理図 (正論理)



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3 Pin Configuration and Functions

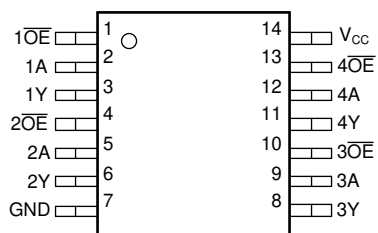


図 3-1. D Package, 14-Pin SOIC; PW Package, TSSOP-14 PIN (Top View)

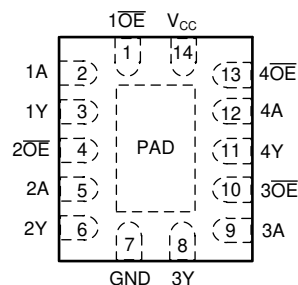


図 3-2. BQA Package, 14-Pin WQFN (Top View)

表 3-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
1OE	1	Input	Output Enable
1A	2	Input	Input A
1Y	3	Output	Output Y
2OE	4	Input	Output Enable
2A	5	Input	Input A
2Y	6	Output	Output Y
GND	7	—	Ground
3Y	8	Output	Output Y
3A	9	Input	Input A
3OE	10	Input	Output Enable
4Y	11	Output	Output Y
4A	12	Input	Input A
4OE	13	Input	Output Enable
V _{CC}	14	—	Positive Supply

4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Supply voltage range	–0.5	6.5	V
V_I	Input voltage range	–0.5	6.5	V
V_O	Output voltage range ^{(1) (2)}	–0.5	$V_{CC} + 0.5$	V
I_{IK}	Input clamp current	$V_I < 0$		–50 mA
I_{OK}	Output clamp current	$V_O < 0$		–50 mA
I_O	Continuous output current		±50	mA
	Continuous current through V_{CC} or GND		±100	mA
T_{stg}	Storage temperature range	–65	150	°C
P_{tot}	Power dissipation ^{(3) (4)}	$T_A = -40^{\circ}\text{C}$ to 125°C		500 mW

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of V_{CC} is provided in the recommended operating conditions table.

(3) For the D package: above 70°C , the value of P_{tot} derates linearly with 8 mW/K.

(4) For the PW package: above 60°C , the value of P_{tot} derates linearly with 5.5 mW/K.

4.2 ESD Ratings

PARAMETER	DEFINITION	VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
	Charged device model (CDM), per AEC Q100-011	±1000	

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			$T_A = 25^{\circ}\text{C}$		-40°C to 125°C		UNIT
			MIN	MAX	MIN	MAX	
V_{CC} Supply voltage	Operating		1.65	3.6	1.65	3.6	V
	Data retention only		1.5		1.5		
V_{IH} High-level input voltage	$V_{CC} = 1.65\text{V}$ to 1.95V		$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		V
	$V_{CC} = 2.3\text{V}$ to 2.7V		1.7		1.7		
	$V_{CC} = 2.7\text{V}$ to 3.6V		2		2		
V_{IL} Low-level input voltage	$V_{CC} = 1.65\text{V}$ to 1.95V		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		V
	$V_{CC} = 2.3\text{V}$ to 2.7V			0.7		0.7	
	$V_{CC} = 2.7\text{V}$ to 3.6V			0.8		0.8	
V_I Input voltage			0	5.5	0	5.5	V
V_O Output voltage			0	V_{CC}	0	V_{CC}	V
I_{OH} High-level output current	$V_{CC} = 1.65\text{V}$			–4		–4	mA
	$V_{CC} = 2.3\text{V}$			–8		–8	
	$V_{CC} = 2.7\text{V}$			–12		–12	
	$V_{CC} = 3\text{V}$			–24		–24	
I_{OL} Low-level output current	$V_{CC} = 1.65\text{V}$			4		4	mA
	$V_{CC} = 2.3\text{V}$			8		8	
	$V_{CC} = 2.7\text{V}$			12		12	
	$V_{CC} = 3\text{V}$			24		24	

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	$T_A = 25^\circ\text{C}$		$-40^\circ\text{C to } 125^\circ\text{C}$		UNIT
	MIN	MAX	MIN	MAX	
$\Delta t/\Delta v$ Input transition rise or fall rate		8		8	ns/V

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

4.4 Thermal Information

THERMAL METRIC ⁽¹⁾		BQA (WQFN)	D (SOIC)	PW (TSSOP)	UNIT
		14 PINS			
R _{θJA}	Junction-to-ambient thermal resistance	102.3	127.8	150.8	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

Not recommended operating into air temperature range (unless otherwise noted)								
PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			−40°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	
V _{OH}	I _{OH} = −100μA	1.65V to 3.6 V	V _{CC} − 0.2			V _{CC} − 0.2		V
	I _{OH} = −4mA	1.65V	1.29			1.1		
	I _{OH} = −8mA	2.3V	1.9			1.75		
	I _{OH} = −12mA	2.7V	2.2			2.1		
		3V	2.4			2.35		
	I _{OH} = −24mA	3V	2.3			2.1		
V _{OL}	I _{OL} = 100μA	1.65V to 3.6 V	0.1			0.2		V
	I _{OL} = 4mA	1.65V	0.24			0.45		
	I _{OL} = 8mA	2.3V	0.3			0.7		
	I _{OL} = 12mA	2.7V	0.4			0.5		
	I _{OL} = 24mA	3V	0.55			0.7		
I _I	V _I = 5.5 V or GND	3.6V	±1			±10		μA
I _{OZ}	V _O = V _{CC} or GND	3.6V	±1			±10		μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	3.6V	1			20		μA
ΔI _{CC}	One input at V _{CC} − 0.6 V, Other inputs at V _{CC} or GND	2.7V to 3.6 V	500			500		μA
C _i	V _I = V _{CC} or GND	3.3V	5					pF

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

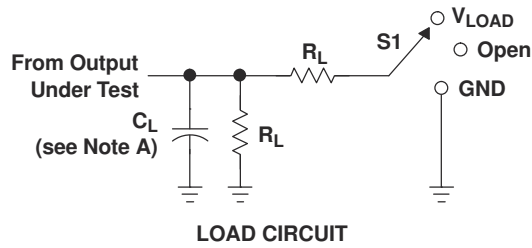
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C to } 125^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
t_{pd}	A	Y	2.7V	1	3	5.3	1	7	ns
			$3.3\text{V} \pm 0.3\text{V}$	1	2.5	4.6	1	6	
t_{en}	$\overline{OE}$	Y	2.7V	1	3.3	6.4	1	8.5	ns
			$3.3\text{V} \pm 0.3\text{V}$	1	2.4	5.2	1	7	
t_{dis}	$\overline{OE}$	Y	2.7V	1	2.5	4.8	1	6.5	ns
			$3.3\text{V} \pm 0.3\text{V}$	1	2.4	4.4	1	6	
$t_{sk(o)}$			$3.3\text{V} \pm 0.3\text{V}$				1.5		ns

4.7 Operating Characteristics

$T_A = 25^\circ\text{C}$

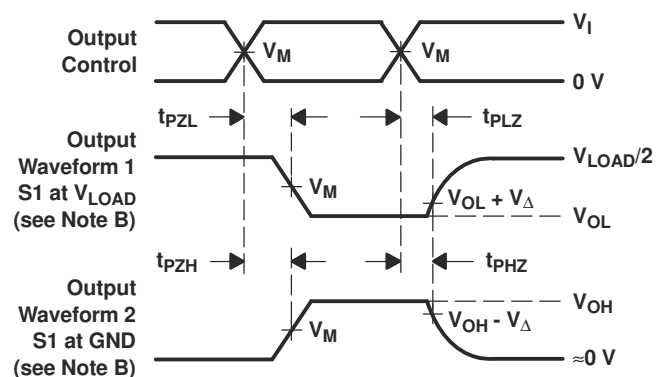
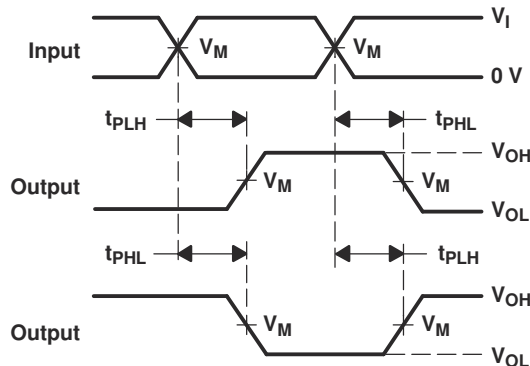
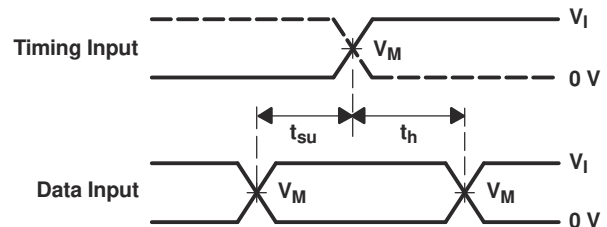
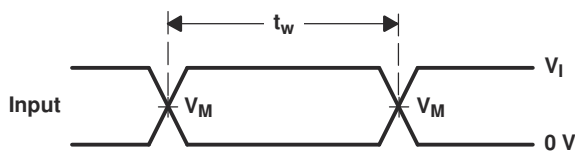
PARAMETER		TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance per gate	$f = 10\text{MHz}$	3.3V	15	pF

5 Parameter Measurement Information



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUT		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
2.7 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \Omega$.
 - The outputs are measured one at a time, with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .
 - All parameters and waveforms are not applicable to all devices.

图 5-1. Load Circuit and Voltage Waveforms

6 Detailed Description

6.1 Overview

The SN74LVC125A features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ($\overline{\text{OE}}$) input is high.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

6.2 Functional Block Diagram

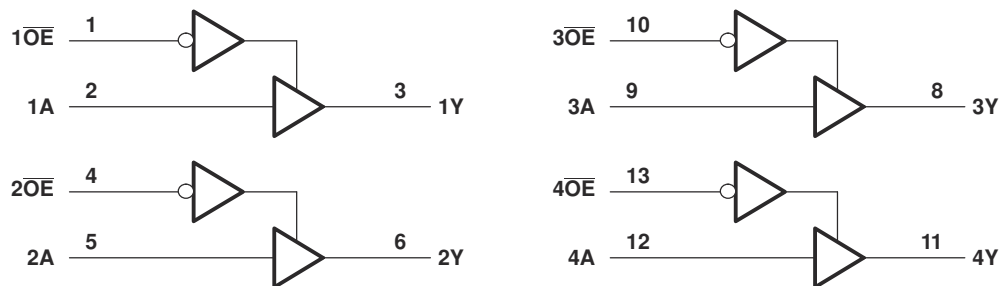


図 6-1. Logic Diagram (Positive Logic)

6.3 Device Functional Modes

Function Table
(Each Buffer)

INPUTS		OUTPUT Y
$\overline{\text{OE}}$	A	
L	H	H
L	L	L
H	X	Z

7 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

7.1 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the [セクション 4.3](#) table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended; if there are multiple VCC pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μF and a 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in [セクション 7.2.2](#) are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient.

7.2.2 Layout Example

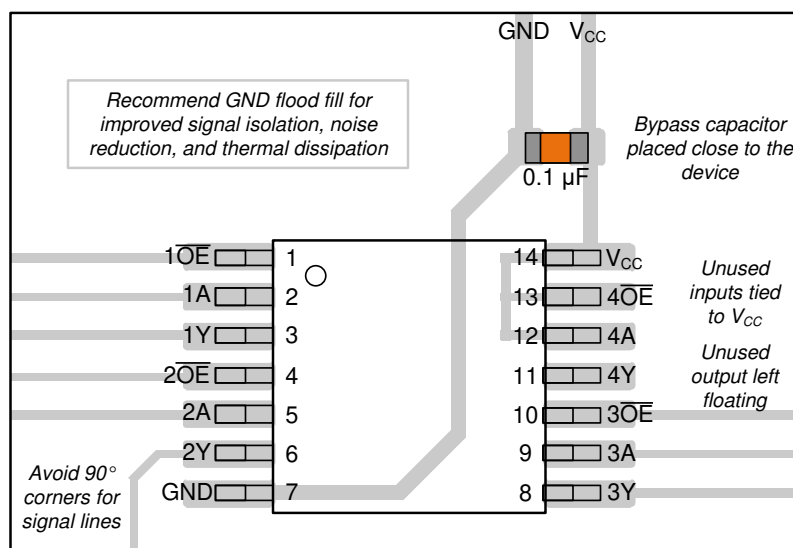


図 7-1. Example layout for the SN74LVC125A-Q1

8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LVC125A-Q1	Click here	Click here	Click here	Click here	Click here

8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.3 サポート・リソース

[テキサス・インスツルメンツ E2E™ サポート・フォーラム](#) は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

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8.4 Trademarks

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8.5 静電気放電に関する注意事項



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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

Changes from Revision D (May 2024) to Revision E (December 2024)	Page
• Updated RθJA values: D = 86 to 127.8, all values in °C/W	5

Changes from Revision C (February 2024) to Revision D (May 2024)	Page
• Updated RθJA values: PW = 113 to 150.8, all values in °C/W	5

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CLVC125AQPWRG4Q1	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
CLVC125AQPWRG4Q1.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQDRQ1	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQDRQ1.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQDRQ1.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQPWRQ1	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQPWRQ1.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQPWRQ1.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AWBQARQ1	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125Q
SN74LVC125AWBQARQ1.A	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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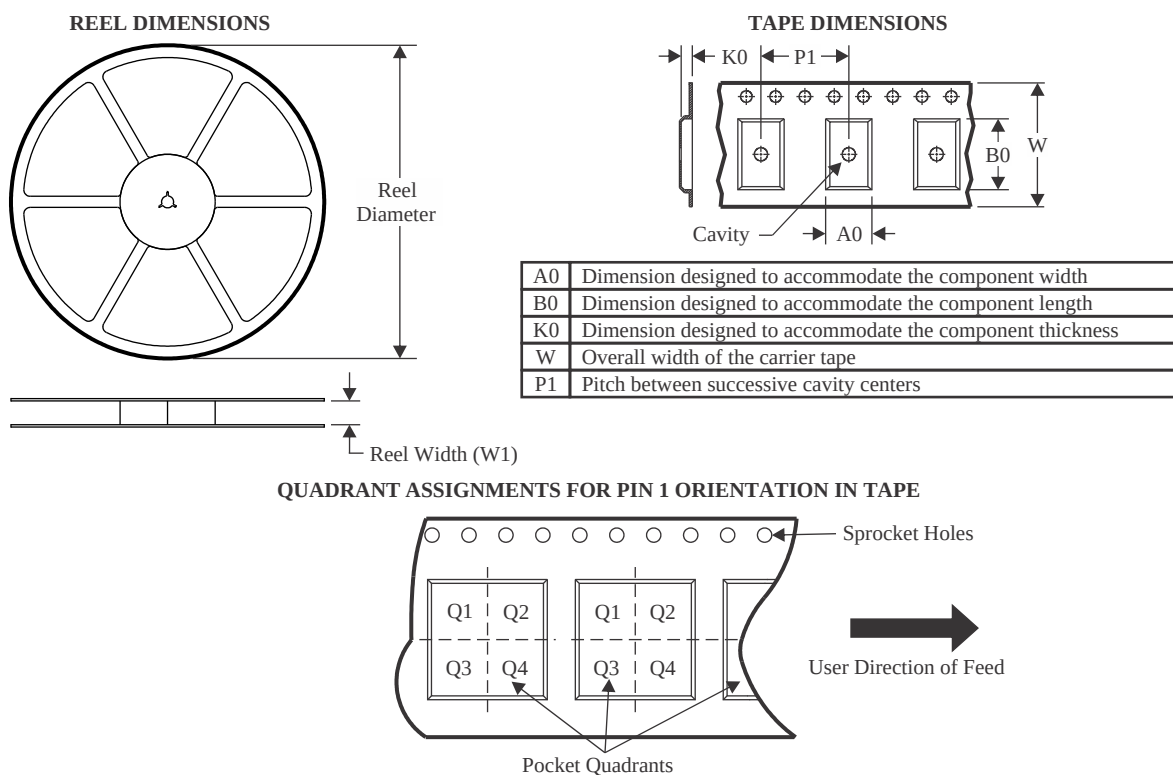
OTHER QUALIFIED VERSIONS OF SN74LVC125A-Q1 :

- Catalog : [SN74LVC125A](#)
- Enhanced Product : [SN74LVC125A-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

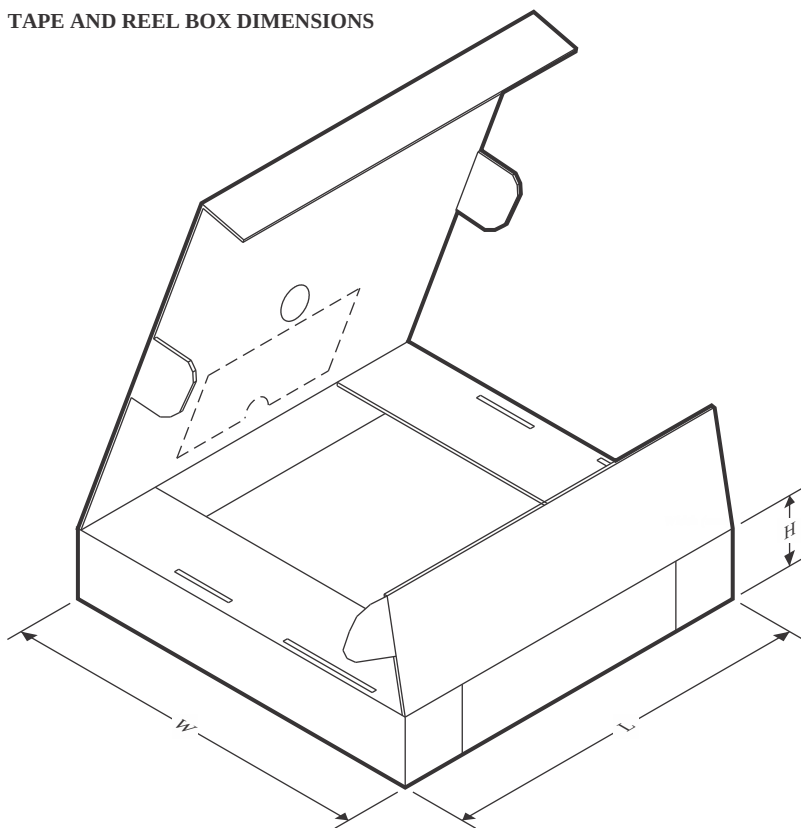
TAPE AND REEL INFORMATION



*All dimensions are nominal

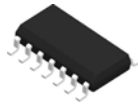
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

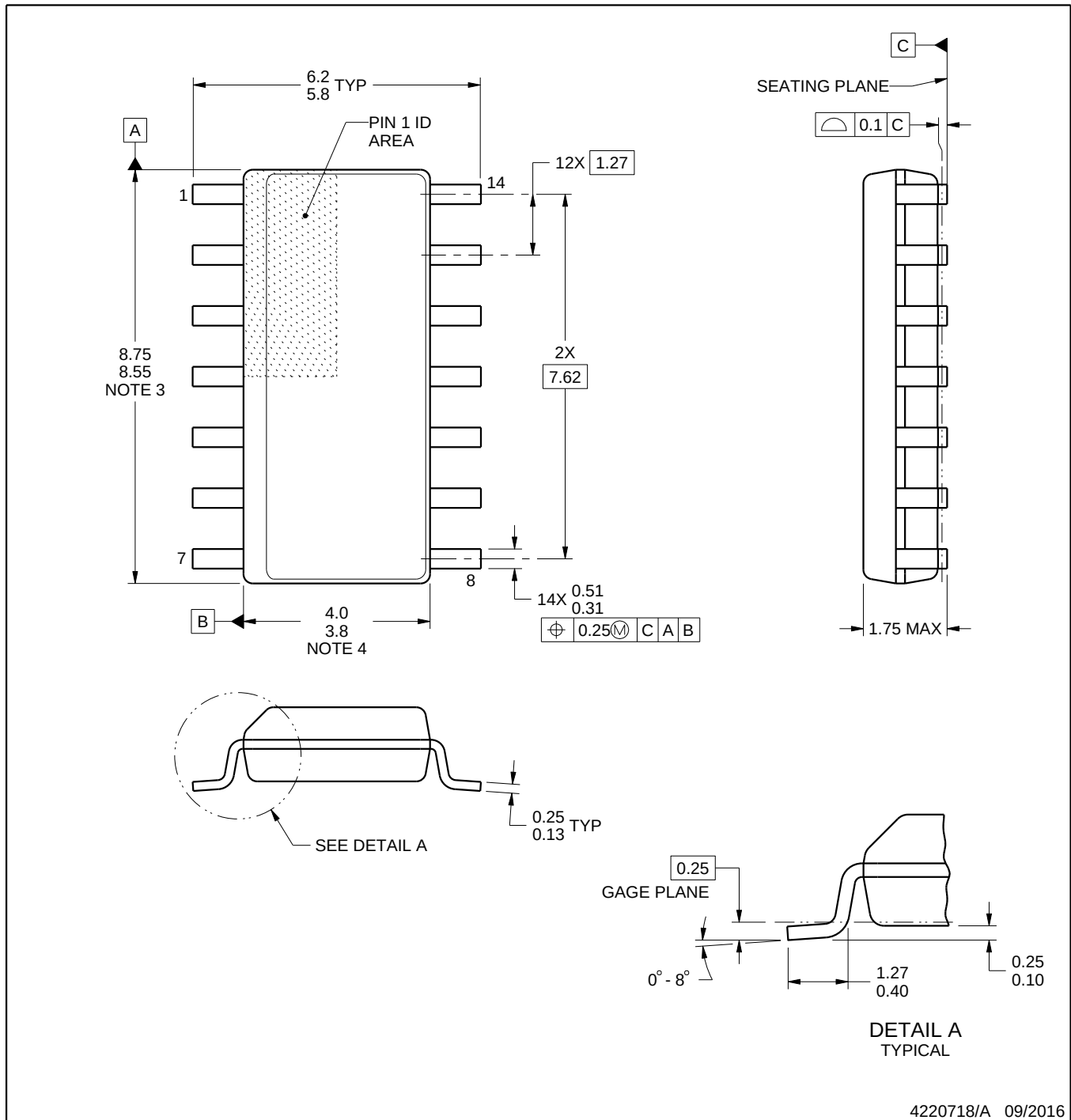


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT

**NOTES:**

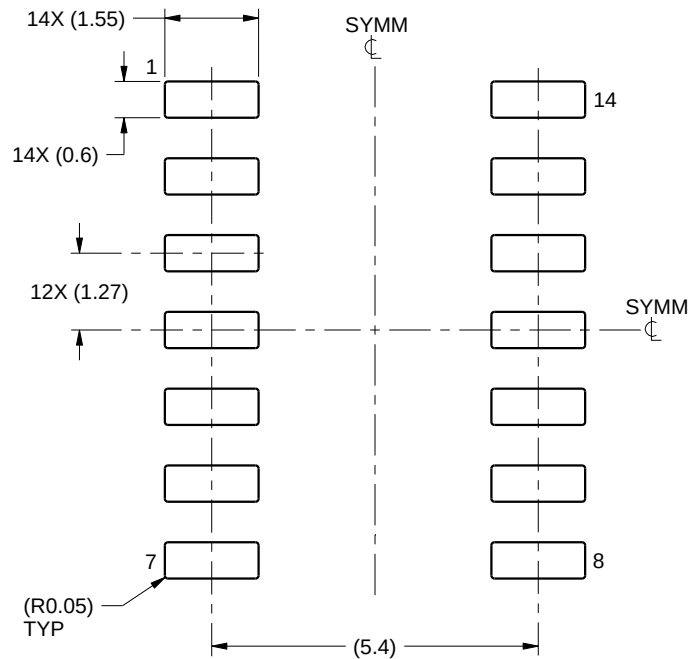
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

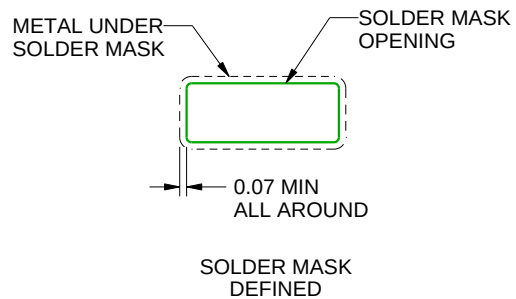
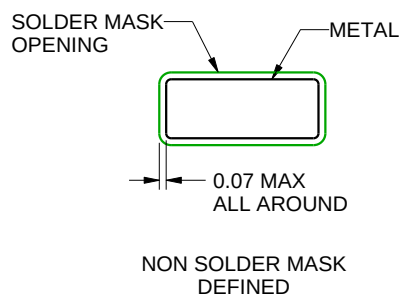
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

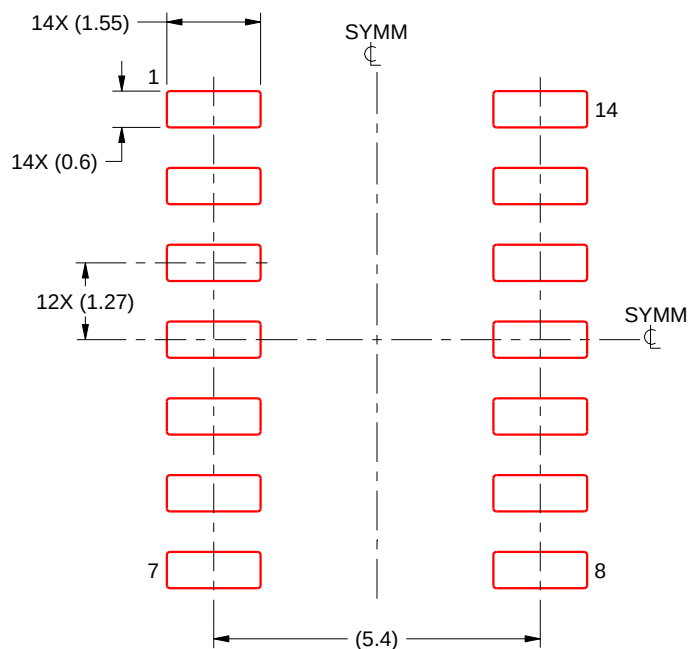
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

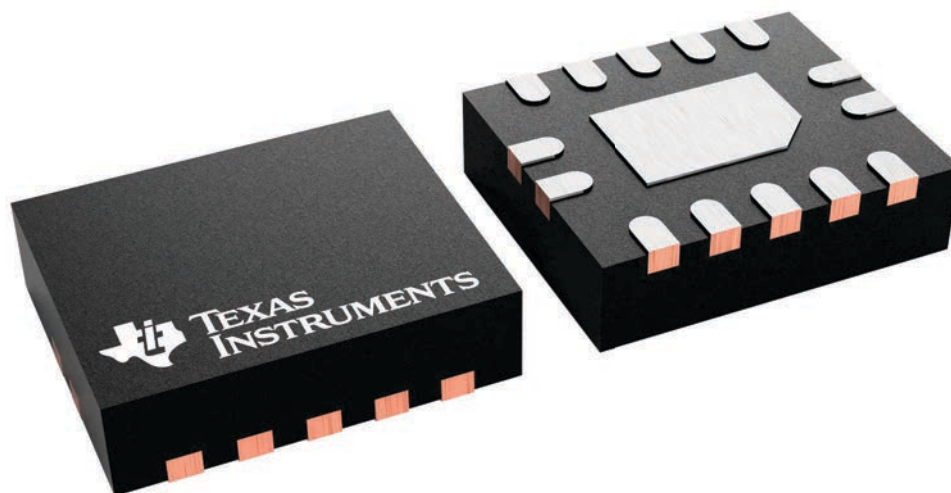
BQA 14

WQFN - 0.8 mm max height

2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4227145/A

WQFN - 0.8 mm max height

[illegible]

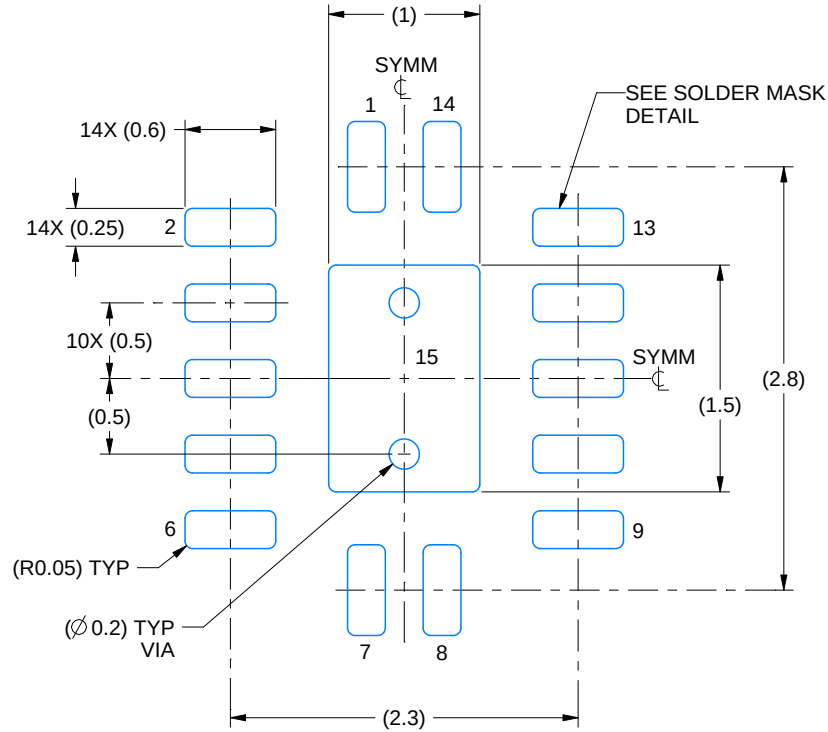
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

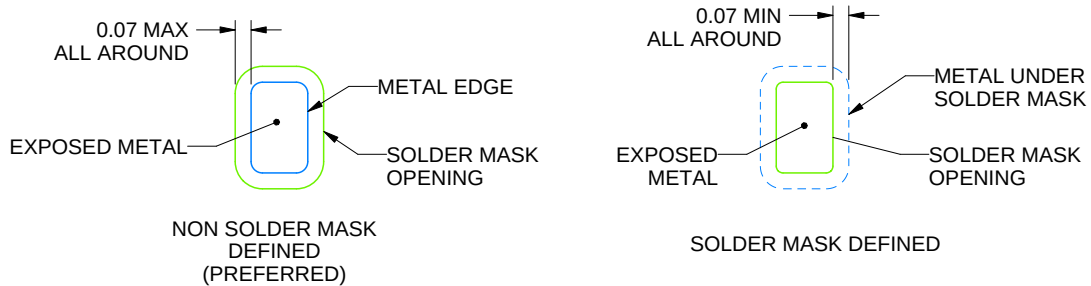
BQA0014B

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



SOLDER MASK DETAILS

4227062/B 09/2021

NOTES: (continued)

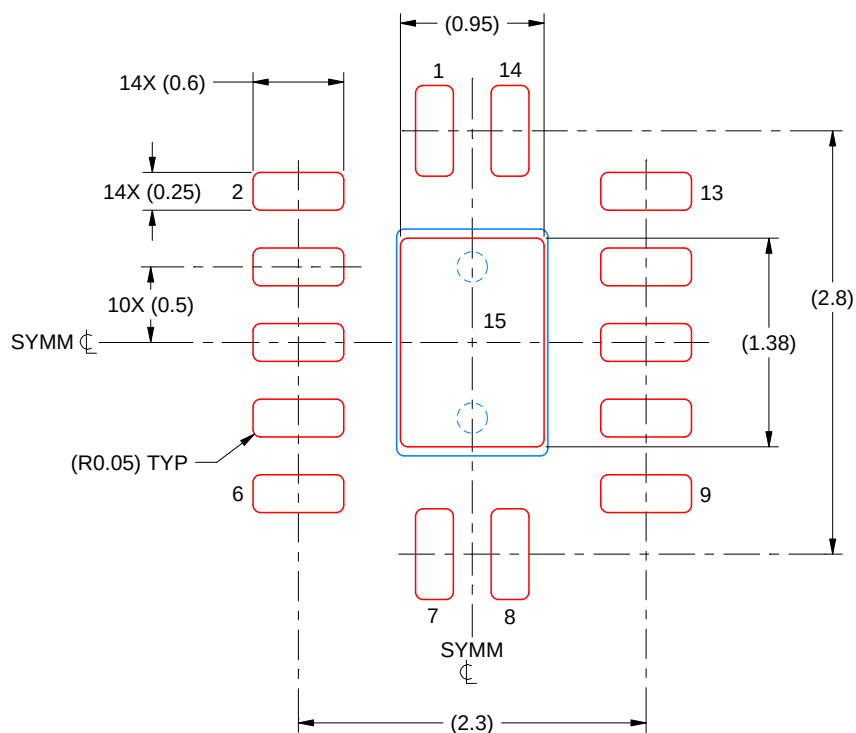
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

BQA0014B

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



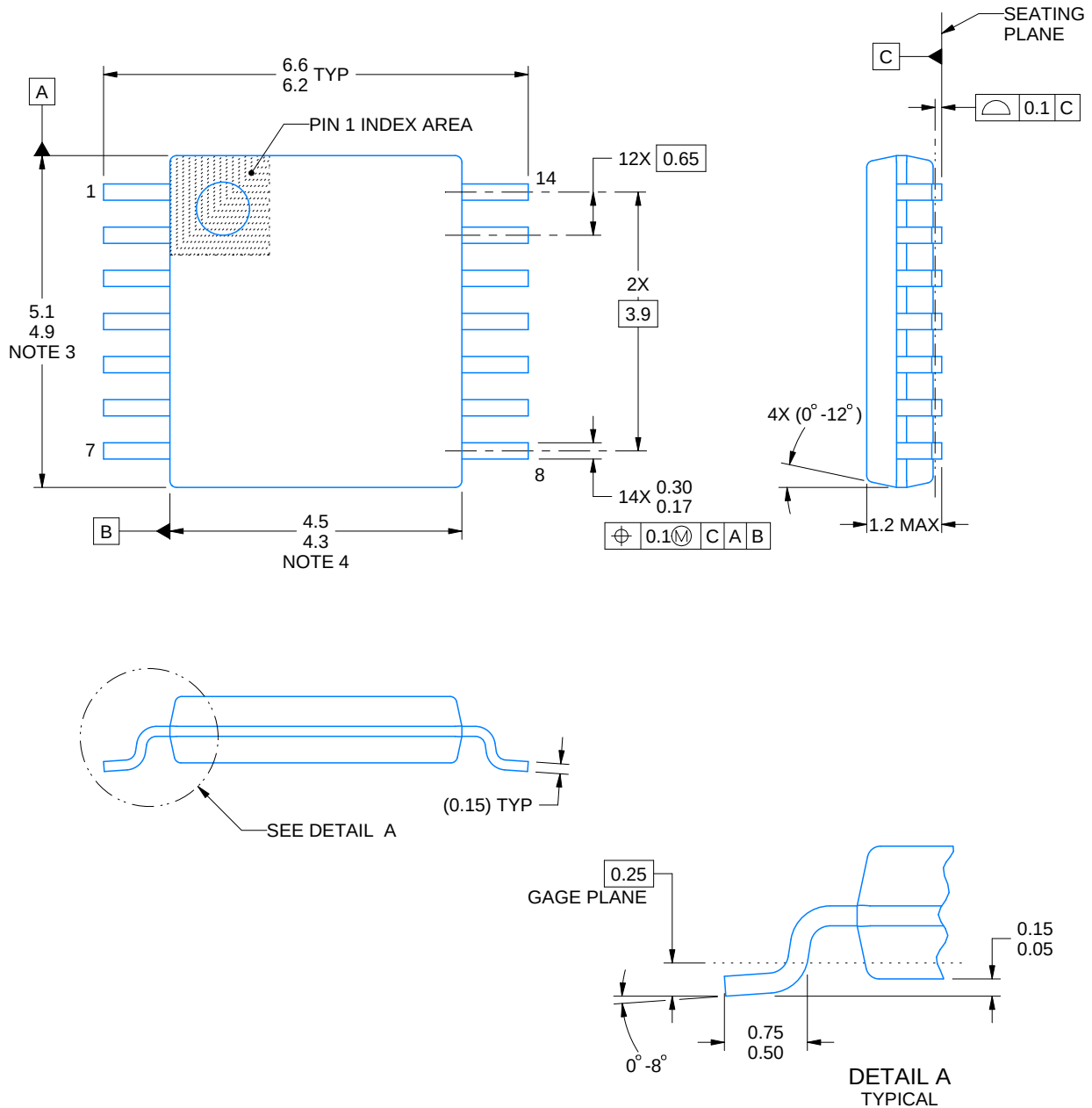
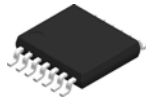
SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

EXPOSED PAD 15
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4227062/B 09/2021

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4220202/B 12/2023

NOTES:

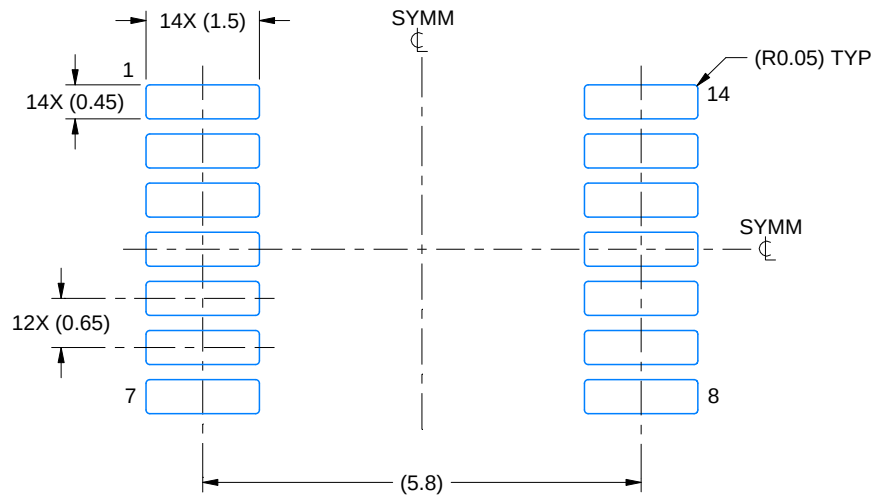
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

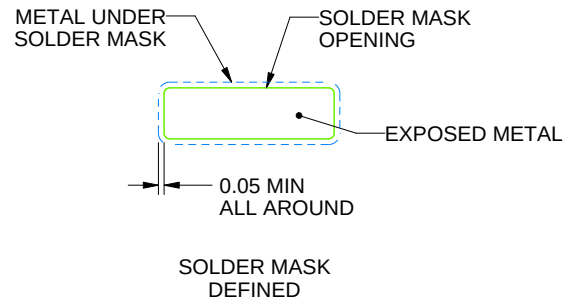
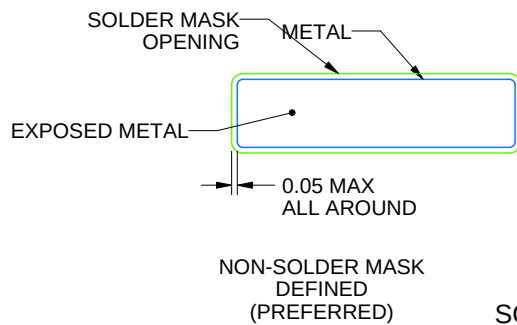
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

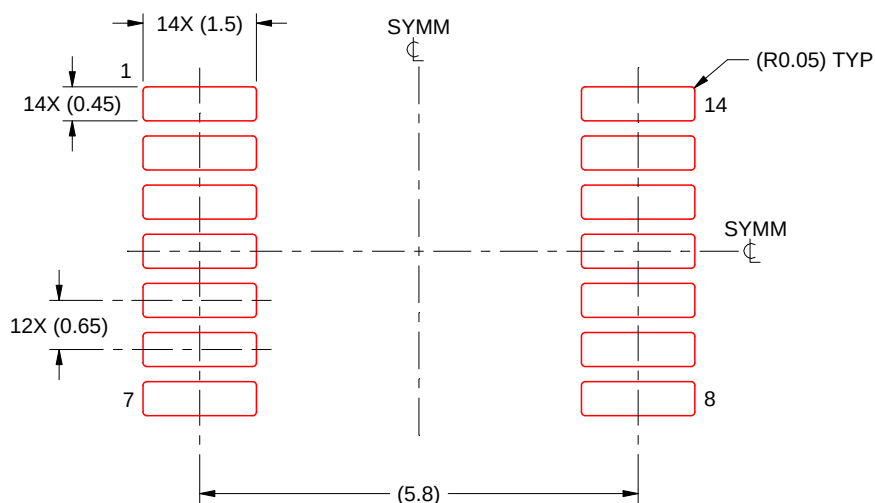
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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